Nch 600V 35A Power MOSFET

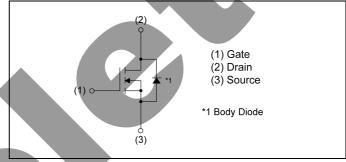
V _{DSS}	600V
R _{DS(on)} (Max.)	0.102Ω
I _D	±35A
P _D	379W

● Outline TO-247

Features

- 1) Low on-resistance.
- 2) Ultra fast switching speed.
- 3) Parallel use is easy.
- 4) Pb-free lead plating; RoHS compliant

•Inner circuit



Packaging specifications

achag	ing specifications	
	Packing	Tube
	Reel size (mm)	-
Tuna	Tape width (mm)	-
Туре	Basic ordering unit (pcs)	450
	Taping code	C9
	Marking	R6035KNZ1
		<u> </u>

Application

Switching

● **Absolute maximum ratings** (T_a = 25°C ,unless otherwise specified)

Parameter	Symbol	Value	Unit	
Drain - Source voltage	V _{DSS}	600	V	
Continuous drain current (T _c = 25°	I _D *1	±35	А	
Pulsed drain current	I _{DP} *2	±105	А	
Cata Cauraa valtaga	static	V	±20	V
Gate - Source voltage AC(f>1Hz)		V_{GSS}	±30	V
Avalanche current, single pulse		I _{AS}	6.6	А
Avalanche energy, single pulse		E _{AS} *3	796	mJ
Power dissipation (T _c = 25°C)		P _D	379	W
Junction temperature		T _j	150	°C
Operating junction and storage ten	nperature range	T _{stg}	-55 to +150	°C

●Thermal resistance

Downwortow	Cymah al	Values			l lesit
Parameter	Symbol	Min.	Тур.	Max.	Unit
Thermal resistance, junction - case	R _{thJC} *4	-	-	0.33	°C/W
Thermal resistance, junction - ambient	R _{thJA}	-	-	30	°C/W
Soldering temperature, wavesoldering for 10s	T _{sold}	-	-	265	°C

● Electrical characteristics (T_a = 25°C)

Darameter	Cumb al	Conditions	Values			Unit
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Offic
Drain - Source breakdown voltage	V _{(BR)DSS}	$V_{GS} = 0V$, $I_D = 1mA$	600	-	-	V
		$V_{DS} = 600V, V_{GS} = 0V$				
Zero gate voltage drain current	I _{DSS}	$T_j = 25^{\circ}C$	-	-	100	μΑ
		$T_j = 125^{\circ}C$	-	-	1000	
Gate - Source leakage current	I _{GSS}	$V_{GS} = \pm 20V, V_{DS} = 0V$	-	ı	±100	nA
Gate threshold voltage	V _{GS(th)}	$V_{DS} = 10V, I_{D} = 1mA$	3	1	5	V
		$V_{GS} = 10V, I_D = 18.1A$				
Static drain - source on - state resistance	R _{DS(on)} *5	$T_j = 25^{\circ}C$	-	0.092	0.102	Ω
		$T_j = 125^{\circ}C$	-	0.200	-	
Gate resistance	R_{G}	f = 1MHz, open drain	-	1.0	-	Ω



● Electrical characteristics (T_a = 25°C)

Darramatar	Symbol	Conditions	Values			Linit
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Forward Transfer Admittance	Y _{fs} *5	V _{DS} = 10V, I _D = 17.5A	11	22	-	S
Input capacitance	C _{iss}	V _{GS} = 0V	-	3000	-	
Output capacitance	C _{oss}	V _{DS} = 25V	1	2300		pF
Reverse transfer capacitance	C_{rss}	f = 1MHz	1	80	\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \	
Turn - on delay time	$t_{d(on)}^{*5}$	$V_{DD} \simeq 300V$, $V_{GS} = 10V$		45	1	
Rise time	t _r *5	I _D = 17.5A		150) '	no
Turn - off delay time	t _{d(off)} *5	$R_L \simeq 17.4\Omega$		90	-	ns
Fall time	t _f *5	$R_G = 10\Omega$		95	-	

● Gate charge characteristics (T_a = 25°C)

Parameter	Symbol	Conditions	Values			Unit
- Farameter			Min.	Тур.	Max.	Offic
Total gate charge	Q_g^{*5}	$V_{DD} \simeq 300V$	-	72	1	
Gate - Source charge	Q _{gs} *5	I _D = 35A	-	20	1	nC
Gate - Drain charge	Q _{gd} *5	V _{GS} = 10V	1	30	ı	
Gate plateau voltage	V _(plateau)	$V_{DD} \simeq 300V$, $I_D = 35A$	-	6.6	-	V

^{*1} Limited only by maximum channel temperature allowed.

^{*2} Pw ≤ 10µs, Duty cycle ≤ 1%

^{*3} L \doteqdot 500 μ H, V_{DD}=50V, R_G=25 Ω , STARTING T $_{j}$ =25 $^{\circ}$ C

^{*4} T_C=25°C

^{*5} Pulsed

●Body diode electrical characteristics (Source-Drain) (T_a = 25°C)

Daramatar	Symbol	Canditions	Values			Unit
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Uniit
Continuous forward current	I _S *1	T - 25°C	1	1	35	А
Pulse forward current	I _{SP} *2	T _C = 25°C	-	-	105	A
Forward voltage	V _{SD} *5	$V_{GS} = 0V, I_{S} = 35A$	-	-	1.5	V
Reverse recovery time	t _{rr} *5		-	605	- <	ns
Reverse recovery charge	Q _{rr} *5	I _S = 35A di/dt = 100A/µs	-	14.5	-	μC
Peak reverse recovery current	I _{rrm} *5	αναι 100/4μ3	-	45	-	Α

Typical transient thermal characteristics

Symbol	Value	Unit
R _{th1}	0.151	
R _{th2}	0.428	K/W
R _{th3}	0.250	

	Symbol	Value	Unit
$\overline{}$	C _{th1}	0.018	
	C _{th2}	0.400	Ws/K
	C _{th3}	15.4	

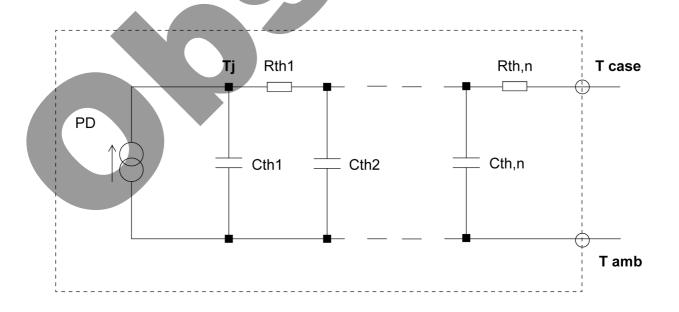


Fig.1 Power Dissipation Derating Curve

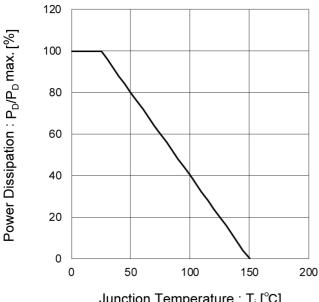
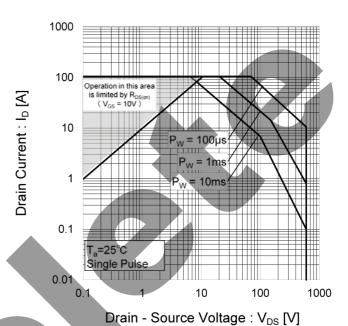
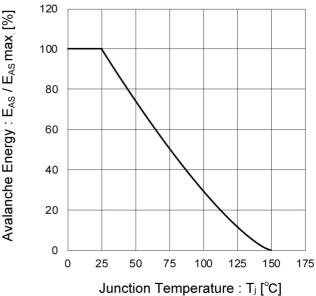


Fig.2 Maximum Safe Operating Area



Junction Temperature : T_i [°C]

Fig.3 Avalanche Energy Derating Curve vs. Junction Temperature



ROHM

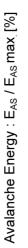


Fig.4 Typical Output Characteristics(I)

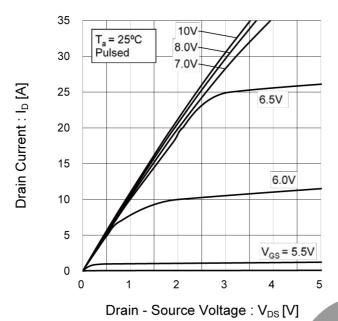


Fig.5 Typical Output Characteristics(II)

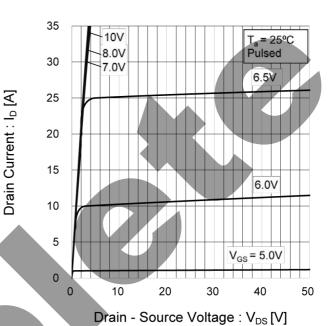




Fig.6 Breakdown Voltage vs.

Junction Temperature

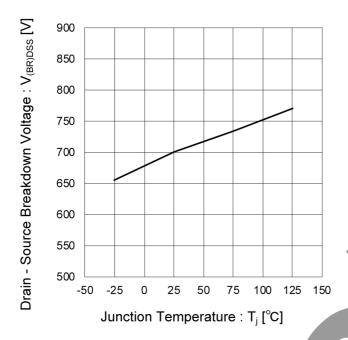


Fig.7 Typical Transfer Characteristics

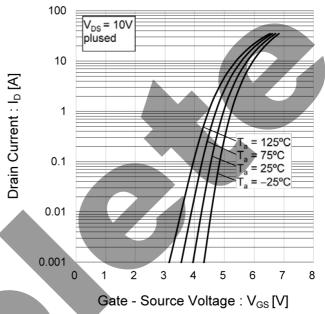


Fig.8 Gate Threshold Voltage vs.
Junction Temperature

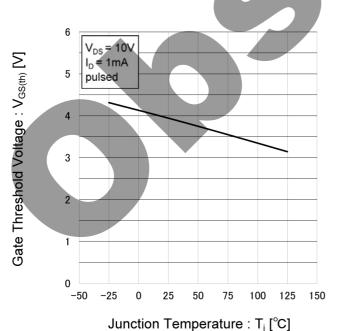


Fig.9 Forward Transfer Admittance vs.

Drain Current

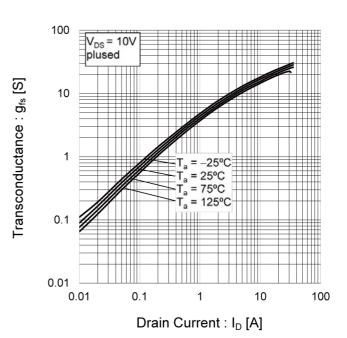


Fig.10 Static Drain - Source On - State
Resistance vs. Gate Source Voltage

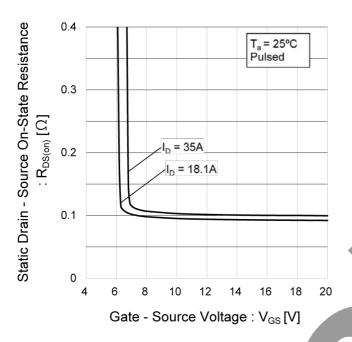


Fig.11 Static Drain - Source On - State Resistance vs. Junction Temperature

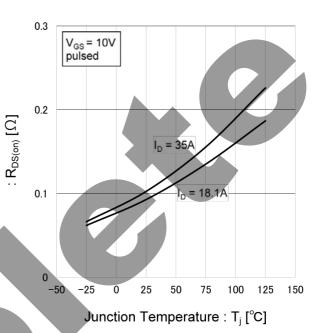
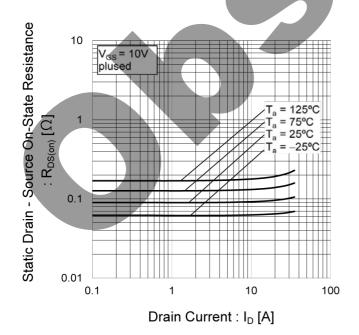


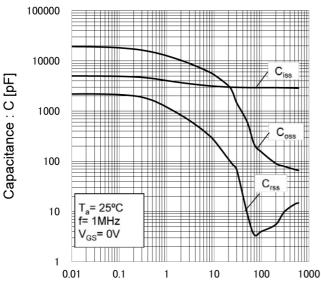
Fig.12 Static Drain - Source On - State Resistance vs. Drain Current(I)



Static Drain - Source On-State Resistance

Fig.13 Typical Capacitance vs.

Drain - Source Voltage



Drain - Source Voltage : V_{DS} [V]

Fig.14 Switching Characteristics

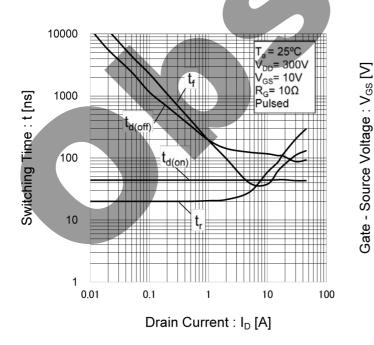
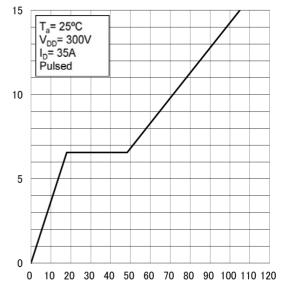
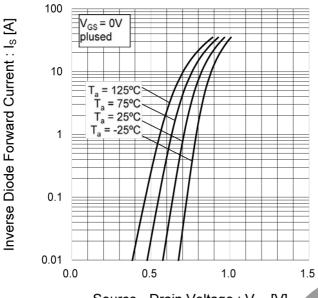


Fig.15 Dynamic Input Characteristics



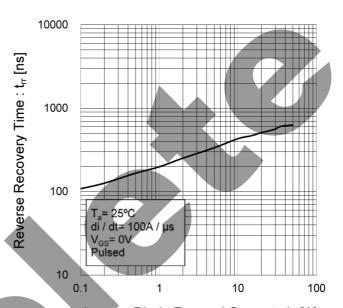
Total Gate Charge : Q_g [nC]

Fig.16 Inverse Diode Forward Current vs. Source - Drain Voltage



Source - Drain Voltage : V_{SD} [V]

Fig.17 Reverse Recovery Time vs. Inverse Diode Forward Current



Inverse Diode Forward Current : Is [A]



Measurement circuits

Fig.1-1 Switching Time Measurement Circuit

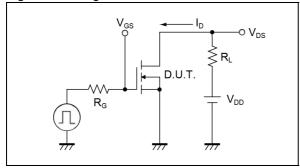


Fig.2-1 Gate Charge Measurement Circuit

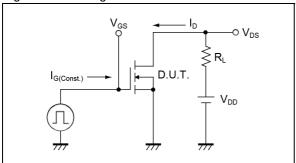


Fig.3-1 Avalanche Measurement Circuit

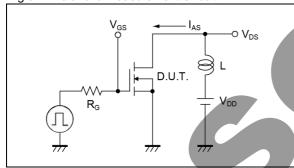


Fig.4-1 dv/dt Measurement Circuit

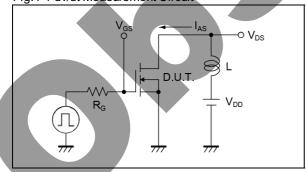


Fig.5-1 dv/dt Measurement Circuit

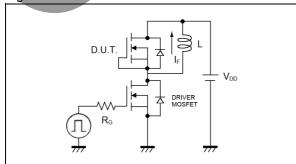


Fig.1-2 Switching Waveforms

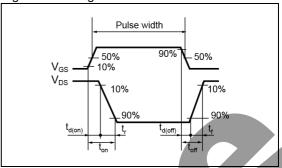


Fig.2-2 Gate Charge Waveform

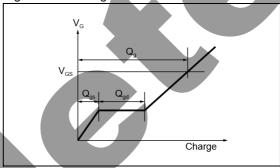


Fig.3-2 Avalanche Waveform

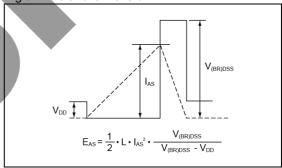


Fig.4-2 dv/dt Waveform

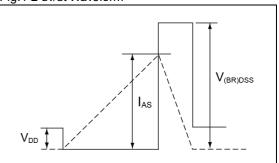
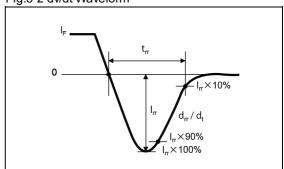
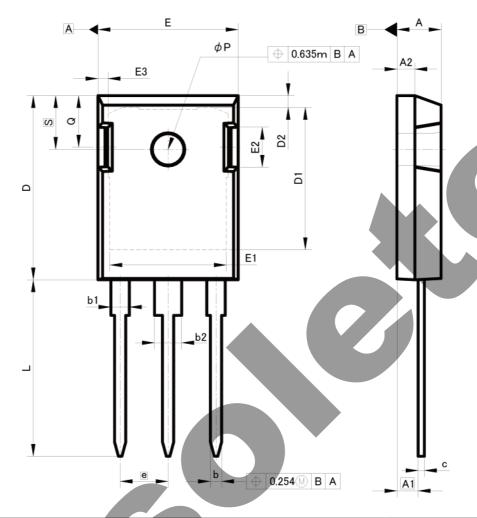


Fig.5-2 dv/dt Waveform



Dimensions

TO-247



DIM	MILIMI	ETERS	INC	HES
DIM	MIN	MAX	MIN	MAX
A	4.83	5.21	0.19	0.205
A1	2.29	2.54	0.09	0.1
A2	1.91	2.16	0.075	0.085
b	1.14	1.40	0.045	0.055
b1	1.91	2.20	0.075	0.087
b2	2.92	3.20	0.115	0.126
С	0.61	0.80	0.024	0.031
D	20.80	21.34	0.819	0.84
D1	17.43	17.83	0.686	0.702
E	15.75	16.13	0.62	0.635
е	5.4	45	0.2	22
N		3		3
L	19.81	20.57	0.78	0.81
L1	3.81	4.07	0.15	0.16
ФР	3.55	3.65	0.14	0.144
Q	5.59	6.20	0.22	0.244
S	6.	15	0.2	24

Dimension in mm/inches



Notice

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1. Our Products are designed and manufactured for application in ordinary electronic equipment (such as AV equipment, OA equipment, telecommunication equipment, home electronic appliances, amusement equipment, etc.). If you intend to use our Products in devices requiring extremely high reliability (such as medical equipment (Note 1), transport equipment, traffic equipment, aircraft/spacecraft, nuclear power controllers, fuel controllers, car equipment including car accessories, safety devices, etc.) and whose malfunction or failure may cause loss of human life, bodily injury or serious damage to property ("Specific Applications"), please consult with the ROHM sales representative in advance. Unless otherwise agreed in writing by ROHM in advance, ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties arising from the use of any ROHM's Products for Specific Applications.

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JAPAN	USA	EU	CHINA
CLASSⅢ	CLASSⅢ	CLASS II b	CI VCCIII
CLASSIV	CLASSIII	CLASSⅢ	CLASSIII

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 - [c] Use of our Products in places where the Products are exposed to sea wind or corrosive gases, including Cl₂, H₂S, NH₃, SO₂, and NO₂
 - [d] Use of our Products in places where the Products are exposed to static electricity or electromagnetic waves
 - [e] Use of our Products in proximity to heat-producing components, plastic cords, or other flammable items
 - [f] Sealing or coating our Products with resin or other coating materials
 - [g] Use of our Products without cleaning residue of flux (Exclude cases where no-clean type fluxes is used. However, recommend sufficiently about the residue.); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
 - [h] Use of the Products in places subject to dew condensation
- 4. The Products are not subject to radiation-proof design.
- 5. Please verify and confirm characteristics of the final or mounted products in using the Products.
- 6. In particular, if a transient load (a large amount of load applied in a short period of time, such as pulse, is applied, confirmation of performance characteristics after on-board mounting is strongly recommended. Avoid applying power exceeding normal rated power; exceeding the power rating under steady-state loading condition may negatively affect product performance and reliability.
- 7. De-rate Power Dissipation depending on ambient temperature. When used in sealed area, confirm that it is the use in the range that does not exceed the maximum junction temperature.
- 8. Confirm that operation temperature is within the specified range described in the product specification.
- 9. ROHM shall not be in any way responsible or liable for failure induced under deviant condition from what is defined in this document.

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- 1. When a highly active halogenous (chlorine, bromine, etc.) flux is used, the residue of flux may negatively affect product performance and reliability.
- 2. In principle, the reflow soldering method must be used on a surface-mount products, the flow soldering method must be used on a through hole mount products. If the flow soldering method is preferred on a surface-mount products, please consult with the ROHM representative in advance.

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Precaution for Electrostatic

This Product is electrostatic sensitive product, which may be damaged due to electrostatic discharge. Please take proper caution in your manufacturing process and storage so that voltage exceeding the Products maximum rating will not be applied to Products. Please take special care under dry condition (e.g. Grounding of human body / equipment / solder iron, isolation from charged objects, setting of lonizer, friction prevention and temperature / humidity control).

Precaution for Storage / Transportation

- 1. Product performance and soldered connections may deteriorate if the Products are stored in the places where:
 - [a] the Products are exposed to sea winds or corrosive gases, including Cl2, H2S, NH3, SO2, and NO2
 - [b] the temperature or humidity exceeds those recommended by ROHM
 - [c] the Products are exposed to direct sunshine or condensation
 - [d] the Products are exposed to high Electrostatic
- 2. Even under ROHM recommended storage condition, solderability of products out of recommended storage time period may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is exceeding the recommended storage time period.
- 3. Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.
- 4. Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

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